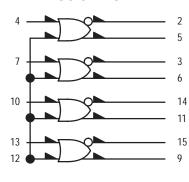
Quad OR/NOR Gate

The MC10H101 is a quad 2–input OR/NOR gate with one input from each gate common to pin 12. This MECL 10H part is a functional/pinout duplication of the standard MECL 10K family part, with 100% improvement in propagation delay, and no increases in power–supply current.

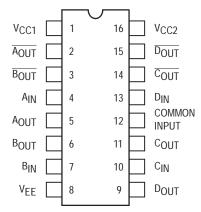
- Propagation Delay, 1.0 ns Typical
- Power Dissipation 25 mW/Gate (same as MECL 10K)
- Improved Noise Margin 150 mV (Over Operating Voltage and Temperature Range)
- Voltage Compensated
- MECL 10K–Compatible

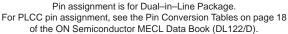


LOGIC DIAGRAM





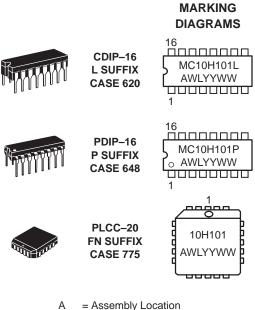






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http://onsemi.com



A = Assembly Location WL = Wafer Lot YY = Year WW = Work Week

ORDERING INFORMATION

| Device | Package | Shipping | | |
|------------|---------|---------------|--|--|
| MC10H101L | CDIP-16 | 25 Units/Rail | | |
| MC10H101P | PDIP-16 | 25 Units/Rail | | |
| MC10H101FN | PLCC-20 | 46 Units/Rail | | |

MAXIMUM RATINGS

| Symbol | Characteristic | Rating | Unit |
|------------------|--|----------------------------|---------|
| VEE | Power Supply ($V_{CC} = 0$) | -8.0 to 0 | Vdc |
| VI | Input Voltage (V _{CC} = 0) | 0 to V _{EE} | Vdc |
| lout | Output Current – Continuous – Surge | 50 100 | mA |
| TA | Operating Temperature Range | 0 to +75 | °C |
| T _{stg} | Storage Temperature Range – Plastic – Ceramic | –55 to +150 –55 to +165 | °C ℃ |

ELECTRICAL CHARACTERISTICS (V_{EE} = $-5.2 \text{ V} \pm 5\%$) (See Note 1.)

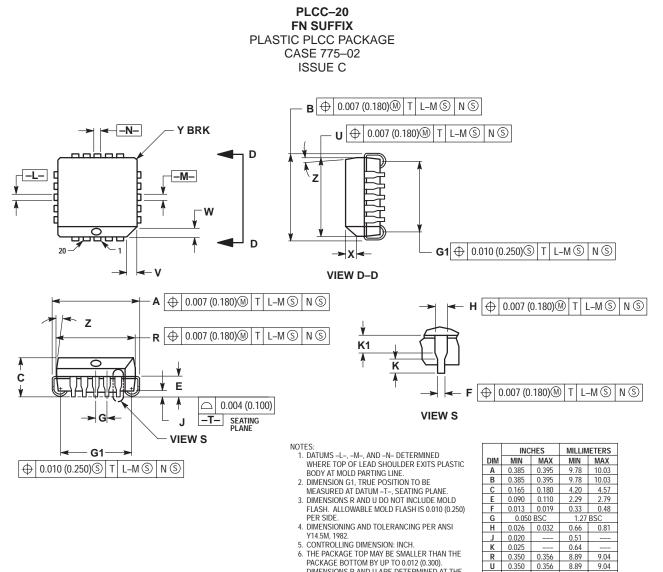
| | | 0 ° | | 25° | | 75° | | |
|------------------|-------------------------------------|------------|------------|-------|------------|-------|------------|------|
| Symbol | Characteristic | Min | Max | Min | Мах | Min | Max | Unit |
| ΙE | Power Supply Current | - | 29 | - | 26 | - | 29 | mA |
| linH | Input Current High (Pin 12 only) | | 425 850 | - | 265 535 | | 265 535 | μA |
| l _{inL} | Input Current Low | 0.5 | - | 0.5 | - | 0.3 | - | μΑ |
| VOH | High Output Voltage | -1.02 | -0.84 | -0.98 | -0.81 | -0.92 | -0.735 | Vdc |
| VOL | Low Output Voltage | -1.95 | -1.63 | -1.95 | -1.63 | -1.95 | -1.60 | Vdc |
| VIH | High Input Voltage | -1.17 | -0.84 | -1.13 | -0.81 | -1.07 | -0.735 | Vdc |
| VIL | Low Input Voltage | -1.95 | -1.48 | -1.95 | -1.48 | -1.95 | -1.45 | Vdc |

AC PARAMETERS

| tŗ | pd | Propagation Delay Pin 12 Only Exclude Pin 12 | 0.5 0.5 | 1.6 1.45 | 0.5 0.5 | 1.6 1.5 | 0.5 0.5 | 1.7 1.6 | ns |
|----|----------------|--|------------|-------------|------------|------------|------------|------------|----|
| 1 | t _r | Rise Time | 0.5 | 2.1 | 0.5 | 2.2 | 0.5 | 2.3 | ns |
| 1 | tf | Fall Time | 0.5 | 2.1 | 0.5 | 2.2 | 0.5 | 2.3 | ns |

 Each MECL 10H series circuit has been designed to meet the dc specifications shown in the test table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 linear fpm is maintained. Outputs are terminated through a 50–ohm resistor to –2.0 volts.

PACKAGE DIMENSIONS



6. THE PACKAGE TOP MAY BE SMALLER THAN THE PACKAGE BOTTOM BY UP TO 0.012 (0.300). DIMENSIONS R AND U ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY EXCLUSIVE OF MOLD FLASH, TIE BAR BURRS, GATE BURRS AND INTERLEAD FLASH, BUT INCLUDING ANY MISMATCH BETWEEN THE TOP AND BOTTOM OF THE PLASTIC BODY.

V 0.042

K1 0.040

Ζ

W 0.042 0.048

X 0.042 0.056 Y ---- 0.020

----2 °

G1 0.310 0.330

0.048

10

1.07

1.07

1.07

----2 °

7.88 8.38

1.02

1.21

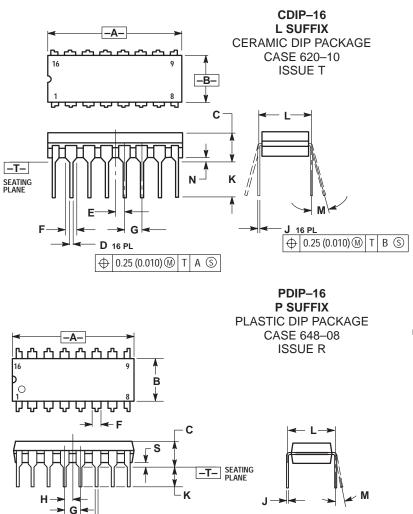
1.21

1.42

0.50

10 °

. DIMENSION H DOES NOT INCLUDE DAMBAR PROTRUSION OR INTRUSION. THE DAMBAR 7. PROTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE GREATER THAN 0.037 (0.940). THE DAMBAR INTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE SMALLER THAN 0.025 (0.635).



NOTES:

DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

- CONTROLLING DIMENSION: INCH. DIMENSION L TO CENTER OF LEAD WHEN 3
- FORMED PARALLEL. DIMENSION F MAY NARROW TO 0.76 (0.030) 4

WHERE THE LEAD ENTERS THE CERAMIC BODY

| | INC | HES | MILLIMETERS | | |
|-----|-----------|-------|-------------|-------|--|
| DIM | MIN | MAX | MIN | MAX | |
| Α | 0.750 | 0.785 | 19.05 | 19.93 | |
| В | 0.240 | 0.295 | 6.10 | 7.49 | |
| С | | 0.200 | | 5.08 | |
| D | 0.015 | 0.020 | 0.39 | 0.50 | |
| Ε | 0.050 BSC | | 1.27 BSC | | |
| F | 0.055 | 0.065 | 1.40 | 1.65 | |
| G | 0.100 BSC | | 2.54 BSC | | |
| Н | 0.008 | 0.015 | 0.21 | 0.38 | |
| К | 0.125 | 0.170 | 3.18 | 4.31 | |
| L | 0.300 BSC | | 7.62 BSC | | |
| М | 0 ° | 15° | 0 ° | 15 ° | |
| Ν | 0.020 | 0.040 | 0.51 | 1.01 | |

NOTES

- DIMENSIONING AND TOLERANCING PER ANSI 1
- Y14.5M, 1982. CONTROLLING DIMENSION: INCH.

DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL. 3

- DIMENSION B DOES NOT INCLUDE MOLD FLASH. ROUNDED CORNERS OPTIONAL.

| | INC | HES | MILLIMETERS | | |
|-----|-----------|---------|-------------|-------|--|
| DIM | MIN | MIN MAX | | MAX | |
| Α | 0.740 | 0.770 | 18.80 | 19.55 | |
| В | 0.250 | 0.270 | 6.35 | 6.85 | |
| С | 0.145 | 0.175 | 3.69 | 4.44 | |
| D | 0.015 | 0.021 | 0.39 | 0.53 | |
| F | 0.040 | 0.70 | 1.02 | 1.77 | |
| G | 0.100 BSC | | 2.54 BSC | | |
| Н | 0.050 | BSC | 1.27 BSC | | |
| J | 0.008 | 0.015 | 0.21 | 0.38 | |
| К | 0.110 | 0.130 | 2.80 | 3.30 | |
| L | 0.295 | 0.305 | 7.50 | 7.74 | |
| М | 0° 10° | | 0 ° | 10 ° | |
| S | 0.020 | 0.040 | 0.51 | 1.01 | |

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